

# ML1XX2 SERIES

FOR OPTICAL INFORMATION SYSTEMS

TYPE  
NAME

**ML1012R, ML1412R, ML120G2**

## DESCRIPTION

ML1XX2 is a high power AlGaInP semiconductor laser which provides a stable, single transverse mode oscillation with emission wavelength of 685-nm and standard CW light output of 30mW.

ML1XX2 has a window-mirror-facet which improves the maximum output power. That leads to highly reliable and high-power operation.

## FEATURES

- High Power: 30mW (CW), 50mW (pulse)
- Visible Light: 685nm (typ)

## APPLICATION

Optical disc drive (High Density / High Speed)

## ABSOLUTE MAXIMUM RATINGS (Note 1)

Symbol	Parameter	Conditions	Ratings	Unit
Po	Light output power	CW	<b>35</b>	mW
		Pulse(Note 2)	<b>50</b>	
VRL	Reverse voltage (laser diode)	-	<b>2</b>	V
VRD	Reverse voltage (Photodiode)	-	<b>30</b>	V
IFD	Forward current (Photodiode)	-	<b>10</b>	mA
Tc	Case temperature	-	<b>-10~ +60</b>	°C
Tstg	Storage temperature	-	<b>-40~ +100</b>	°C

Note1: The maximum rating means the limitation over which the laser should not be operated even instant time, and this does not mean the guarantee of its lifetime. As for the reliability, please refer to the reliability report from Mitsubishi Semiconductor Quality Assurance Department.

Note2: TARGET SPEC /Condition Duty less than 50%, pulse width less than 1μs

## ELECTRICAL/OPTICAL CHARACTERISTICS (Tc=25°C)

Symbol	Parameter	Test conditions	Min.	Typ.	Max	Unit
Ith	Threshold current	CW	-	<b>35</b>	<b>60</b>	mA
Iop	Operation current	CW,Po=30mW	-	<b>80</b>	<b>120</b>	mA
Vop	Operating voltage	CW,Po=30mW	<b>2.0</b>	<b>2.4</b>	<b>3.0</b>	V
η	Slope efficiency	CW,Po=30mW	-	<b>0.8</b>	-	mW/mA
λp	Peak wavelength	CW,Po=30mW	<b>670</b>	<b>685</b>	<b>700</b>	nm
θ//	Beam divergence angle (parallel)	CW,Po=30mW	<b>7</b>	<b>10</b>	<b>12</b>	°
θ⊥	Beam divergence angle (perpendicular)	CW,Po=30mW	<b>16</b>	<b>20</b>	<b>25</b>	°
Im	Monitoring output current (Photodiode)	CW,Po=30mW VRD=1V RL=10Ω (Note 3)	<b>0.05</b>	<b>0.3</b>	<b>1.5</b>	mA
ID	Dark current (Photodiode)	VRD=10V	<b>0</b>	-	<b>0.5</b>	uA
Ct	Capacitance (Photodiode)	VRD=5V	-	<b>7</b>	-	pF

Note3: RL=the load resistance of photodiode for ML1012R and ML1412R



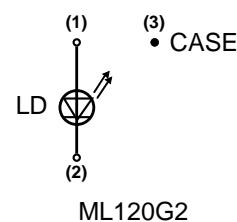
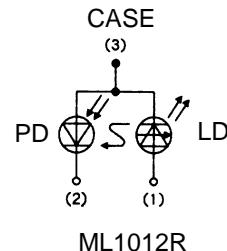
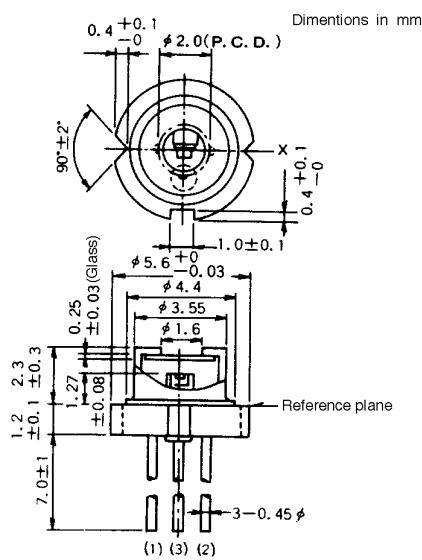
as of February '00

# ML1XX2 SERIES

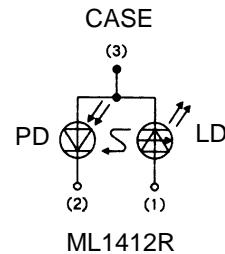
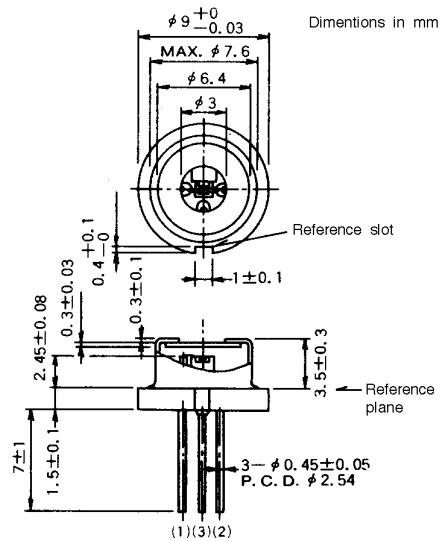
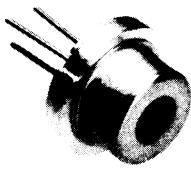
FOR OPTICAL INFORMATION SYSTEMS

## OUTLINE DRAWINGS

**ML1012R  
ML120G2**



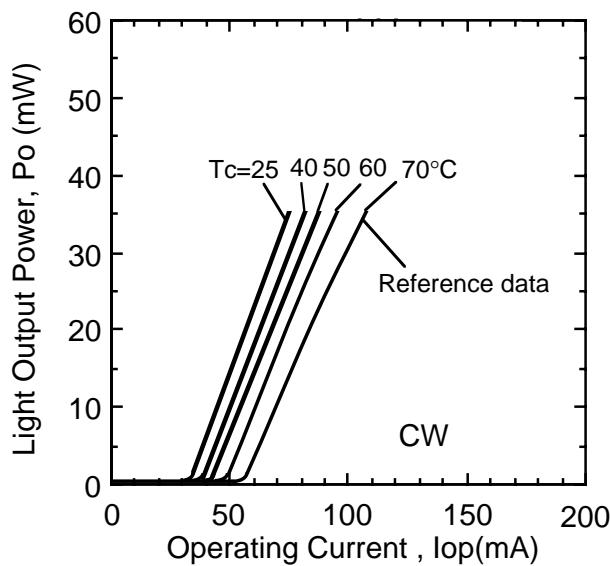
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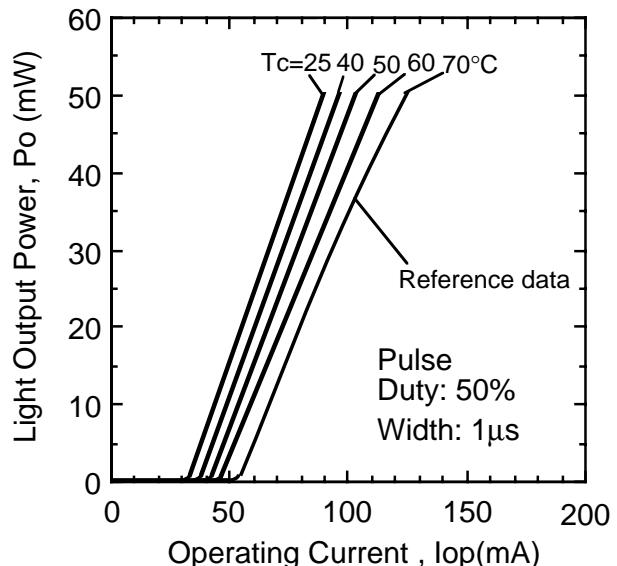
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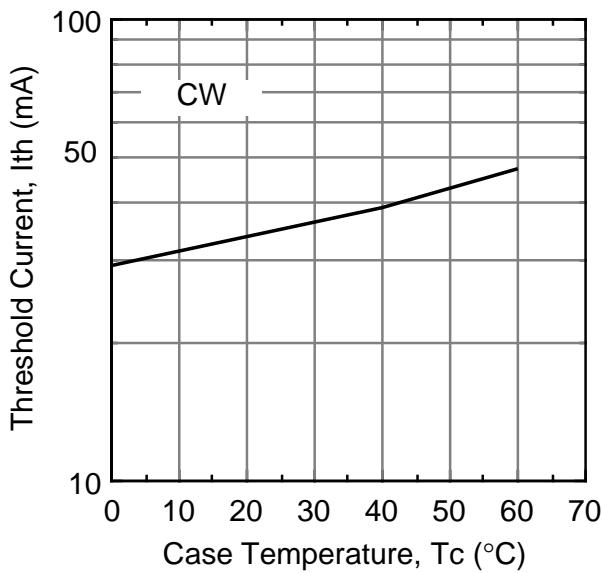
## Typical Characteristics



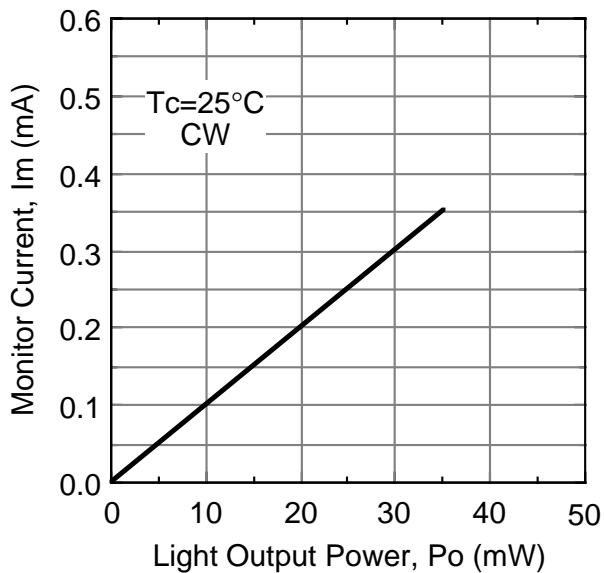
Light Output Power vs. Current (CW)



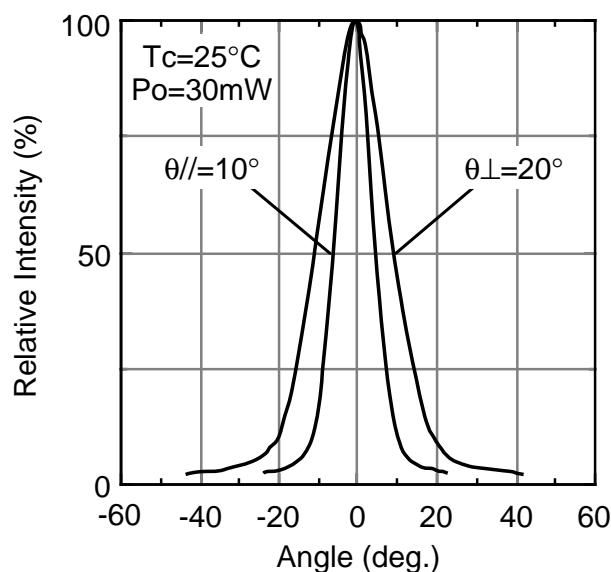
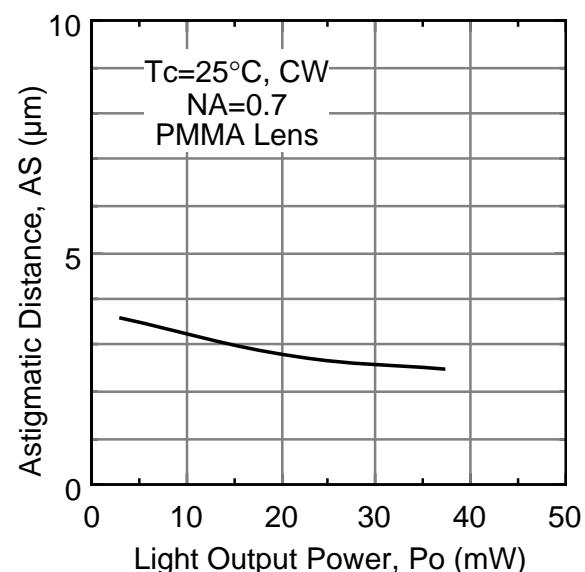
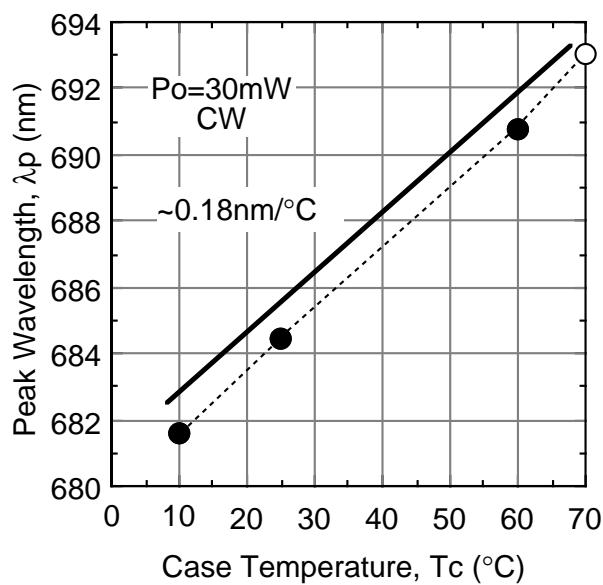
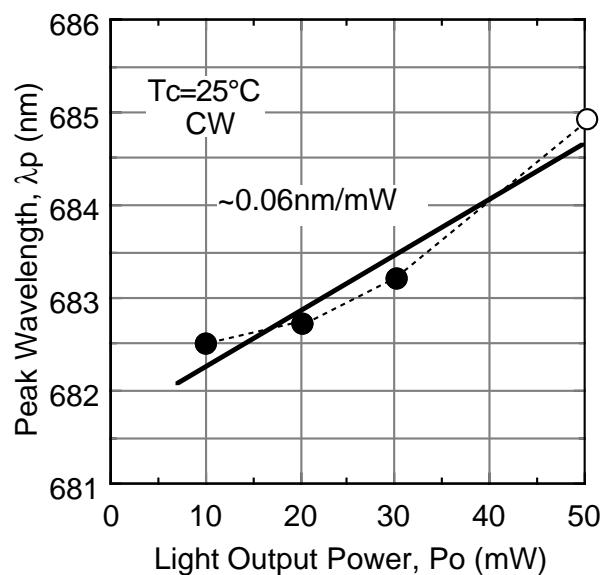
Light Output Power vs. Current (Pulse)



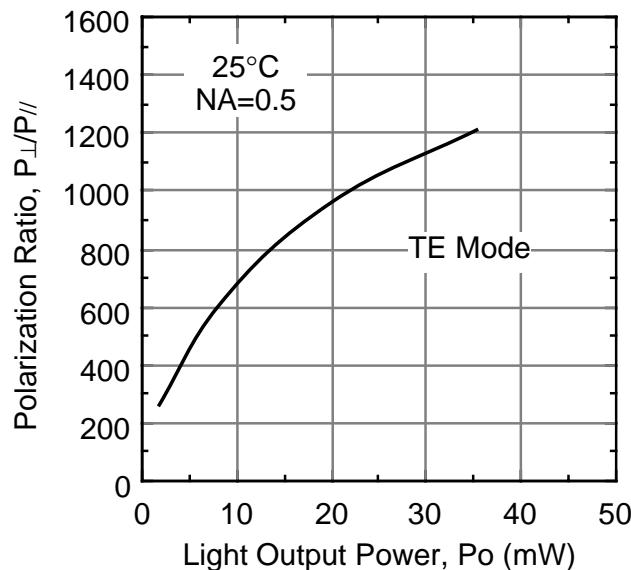
Threshold Current vs. Temperature



Monitor Photodiode Current

Far-Field-PatternsAstigmatic DistancePeak Wavelength vs. TemperaturePeak Wavelength vs. Light Output Power

## Typical Characteristics



Polarization Ratio